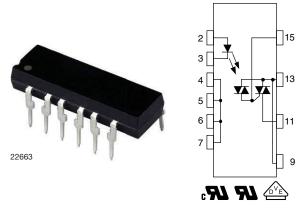


## Vishay Semiconductors

# **Optocoupler, Power Phototriac**



PIN	FUNCTION			
2	LED anode			
3	LED cathode			
4	No connection			
5	No connection			
6	No connection			
7	No connection			
9, 13	Triac T2			
11	Triac T1			
15	Triac gate			

#### **FEATURES**

- Maximum trigger current (I<sub>FT</sub>): 10 mA
- Isolation test voltage 5300 V<sub>RMS</sub>
- Peak off-state voltage 600 V
- Load current 1 A
- dV/dt of 500 V/µs





### **APPLICATIONSFIE**

- Triac driver
- Programable controllers
- AC-output module

### **AGENCY APPROVALS**

- UL E52744 system code H
- CUL E52744 system code H
- VDE DIN EN 60747-5-5 (VDE 0884-5)

#### **DESCRIPTION**

The VO3526 is an optically couple phototriac driving a power triac in a DIP-10 (16) package.

ORDERING INFORMATION				
V O 3 5 2 PART NUMBER	6 - X 0 0 #  PACKAGE OPTION  7.62 mm			
AGENCY CERTIFIED / PACKAGE	TRIGGER, CURRENT I <sub>FT</sub> (mA)			
VDE, UL, cUL	10			
DIP-10, tubes	VO3526			

#### Note

• For additional information on the possible lead bend and VDE options refer to option information.

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT								
LED continuous forward current		I <sub>F</sub>	50	mA				
LED reverse voltage		V <sub>R</sub>	5.0	V				
OUTPUT								
Repetitive peak off-state voltage	Sine wave, 50 to 60 Hz, gate open	$V_{DRM}$	600	V				
On-state RMS current		I <sub>T(RMS)</sub>	1.0	Α				
Peak nonrepetitive surge current (50 Hz, peak)		I <sub>TSM</sub>	10	А				



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER TEST CONDITION SYMBOL VALUE UNIT									
COUPLER									
Total power dissipation		P <sub>diss</sub>	1.2	W					
Ambient temperature range		T <sub>amb</sub>	-40 to +85	°C					
Storage temperature range		T <sub>stg</sub>	-40 to +125	°C					
Soldering temperature (1)	t ≤ 10 s max.	T <sub>sld</sub>	260	°C					
Isolation test voltage	for 1.0 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>					

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to wave profile for soldering conditions for through hole devices
- (2) Total power dissipation value is based on 2S2P PCB. Refer to power phototriac application note for PCB design tips

### **ABSOLUTE MAXIMUM RATING CURVES**

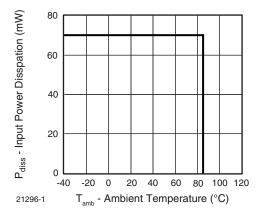


Fig. 1 - Power Dissipation vs. Temperature

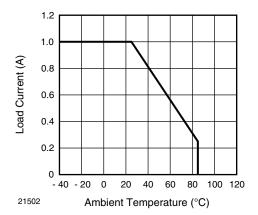


Fig. 2 - Allowable Load Current vs. Ambient Temperature

#### Note

 The allowable load current was calculated out under a given operating conditions and only for reference:
 LED power: Q<sub>E</sub> = 0.015 W, θ<sub>BA</sub> (4-layer) = 30 °C/W

THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
Maximum LED junction temperature	T <sub>jmax.</sub>	105	°C
Maximum NOT junction temperature	T <sub>jmax.</sub>	105	°C
Thermal resistance, junction NOT to bord	$\theta_{NOT-B}$	75	°C/W
Thermal resistance, junction NOT to case	θ <sub>NOT-C</sub>	150	°C/W
Thermal resistance, junction OT to board	$\theta_{OT-B}$	158	°C/W
Thermal resistance, junction OT to case	θ <sub>OT-C</sub>	157	°C/W
Thermal resistance, junction emitter to board	θЕ-В	149	°C/W
Thermal resistance, junction emitter to case	θ <sub>E-C</sub>	161	°C/W
Thermal resistance, junction NOT to junction OT	$\theta_{NOT ext{-}OT}$	243	°C/W
Thermal resistance, junction emitter to junction NOT	$\theta_{E-NOT}$	420	°C/W
Thermal resistance, junction emitter to junction OT	$\theta_{E-OT}$	235	°C/W
Thermal resistance, case to ambient	$\theta_{\sf CA}$	130	°C/W

#### Note

The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the
temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of
PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal
Characteristics of Power Phototriac application note



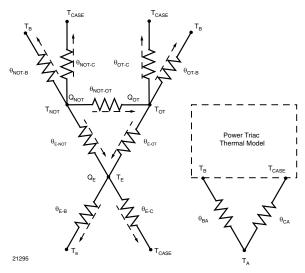
# Vishay Semiconductors

NOT: Non-opto-triac
OT: Opto-triac

T<sub>B</sub>: Board temperatureT<sub>CASE</sub>: Case temperatureT<sub>A</sub>: Ambient temperature

 $\theta_{BA}$ : Thermal resistance, board to ambient

Q<sub>E</sub>: LED power dissipationQ<sub>OT</sub>: OT power dissipationQ<sub>NOT</sub>: NOT power dissipation



Thermal Model

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
LED trigger current	V <sub>T</sub> = 6 V	I <sub>FT</sub>	-	-	10	mA		
Input reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	10	μΑ		
LED forward voltage	$I_F = 10 \text{ mA}$	V <sub>F</sub>	0.9	-	1.4	V		
OUTPUT								
Peak on-state voltage	I <sub>TM</sub> = 1.5 A	V <sub>TM</sub>	-	-	1.7	V		
Repetitive peak off-state current	$V_{DRM} = 600 \text{ V},$ $T_A = 110 ^{\circ}\text{C}, 60 \text{ Hz}$	I <sub>DRM</sub>	-	-	100	μΑ		
Holding current	$R_L = 100 \Omega$	I <sub>H</sub>	-	-	25	mA		
Critical rate of rise of off-state voltage	V <sub>IN</sub> = 400 V (Fig. 3)	dV/dt <sub>cr</sub>	-	210	-	V/µs		
Critical rate of rise of commutating voltage	$V_{IN} = 240 V_{RMS},$ $I_T = 1 A_{RMS}$ (Fig. 3)	dV/dt <sub>crq</sub>	-	0.9	-	V/µs		

#### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements

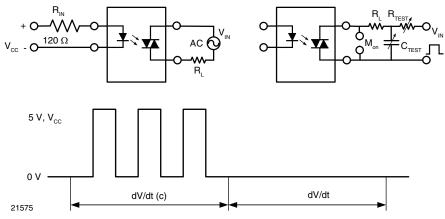


Fig. 3 - dV/dt Test Circuit





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RECOMMENDED OPERATING CONDITIONS									
PARAMETER			TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT		
Forward current at on-state	Forward current at on-state			I <sub>F(ON)</sub>	10	20	mA		
Forward current at off-state		Input		I <sub>F(OFF)</sub>	0	0.1	mA		
Load supply voltage			With snubber (0.022 $\mu$ F, 47 $\Omega$ )	V <sub>OUT(RMS)</sub>	-	240	V		
On-state RMS current	T <sub>A</sub> = 40 °C	Output	On 4-layer PCB	1	-	0.8	Α		
$T_A = 60  ^{\circ}\text{C}$			$(R_{BA} = 30 \text{ °C/W})$	IOUT(RMS)	-	0.6	Α		
Frequency	Frequency			f	50	60	Hz		
Operating temperature					- 40	85	°C		

PARAMETER		TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification		IEC 68 part 1		-	40 / 85 / 21	-	
Pollution degree		DIN VDE 0109		-	2	-	
Tracking resistance (comparative	tracking index)	Insulation group IIIa	CTI	175	-	-	
Highest allowable overvoltage		Transient overvoltage	V <sub>IOTM</sub>	8000	-	-	V <sub>peak</sub>
Maximum working insulation voltage		Recurring peak voltage	V <sub>IORM</sub>	890	-	-	V <sub>peak</sub>
Insulation resistance at 25 °C		V <sub>IO</sub> = 500 V	R <sub>IS</sub>	-	-	≥ 10 <sup>12</sup>	Ω
Insulation resistance at T <sub>S</sub>		V <sub>IO</sub> = 500 V	R <sub>IS</sub>	-	-	≥ 10 <sup>9</sup>	Ω
Insulation resistance at 100 °C		V <sub>IO</sub> = 500 V	R <sub>IS</sub>	-	-	≥ 10 <sup>11</sup>	Ω
Partial discharge test voltage		Method b, $V_{pd} = V_{IORM} \times 1.6$	$V_{pd}$	-	-	1424	V <sub>peak</sub>
Safety limiting values -	Output power		P <sub>SO</sub>	-	-	2	W
maximum values allowed in the	Input current		I <sub>SI</sub>	-	-	150	mA
event of a failure	Case temperature		T <sub>SI</sub>	-	-	165	°C
Minimum external air gap (clearance)		Measured from input terminals to output terminals, shortest distance through air		≥ 7	-	-	mm
Minimum external tracking (creepage)		Measured from input terminals to output terminals, shortest distance path along body		≥7	-	-	mm

This phototriac coupler is suitable for 'safe electrical insulation' only within the safety ratings. Compliance with safety ratings shall be ensured by means of protective circuits



# Vishay Semiconductors

### **TYPICAL CHARACERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

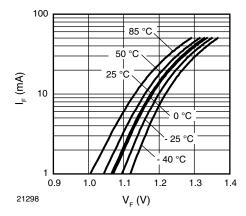


Fig. 4 - Forward Current vs. Forward Voltage

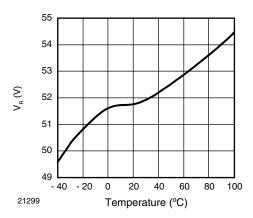


Fig. 5 - Diode Reverse Voltage vs. Temperature

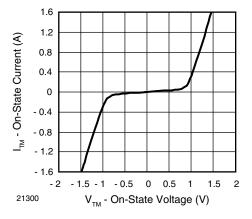


Fig. 6 - On-State Current vs. On State Voltage

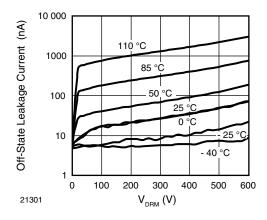


Fig. 7 - Off-State Leakage Current vs. Voltage

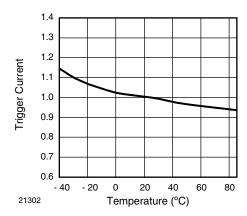


Fig. 8 - Normalized Trigger Input Current vs. Temperature

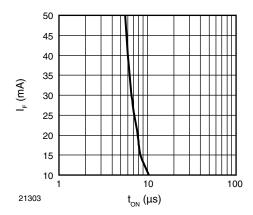


Fig. 9 - Trigger Input Current vs. Turn-on Time



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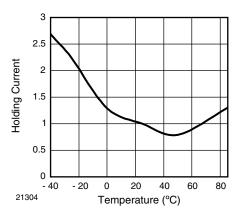


Fig. 10 - Normalized Holding Current vs. Temperature

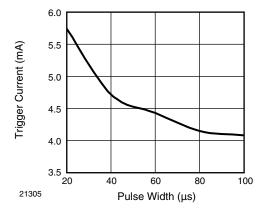


Fig. 11 - Trigger Current vs. Trigger Pulse Width

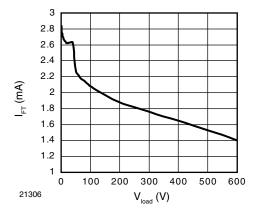
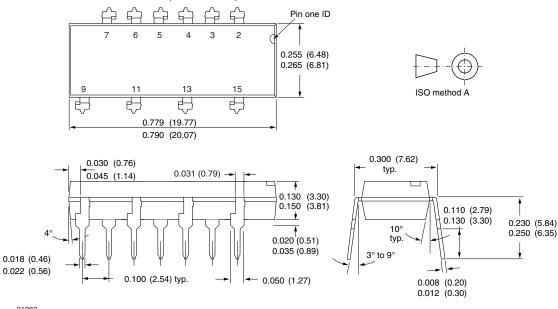


Fig. 12 - Trigger Current vs.  $V_{\text{load}}$ 

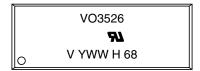


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### **PACKAGE DIMENSIONS** in inches (millimeters)



### **PACKAGE MARKING**





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Vishay

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